Si53102-A1/A2/A3



PCI-EXPRESS GEN 1, GEN 2, GEN 3, AND GEN 4 1:2 Fan-out Clock Buffer

Features

 PCI-Express Gen 1, Gen 2, Gen 3, and Gen 4 common clock compliant

- Two low-power PCIe clock outputs
- Supports Serial-ATA (SATA) at 100 MHz
- No termination resistors required for differential clocks
- 2.5 V or 3.3 V Power supply
- Spread Spectrum Tolerant
- Extended Temperature:

–40 to 85 °C

- Small package 8-pin TDFN (1.4x1.6 mm)
- For PCIe Gen 1: Si53102-A1
- For PCIe Gen 2: Si53102-A2
- For PCIe Gen 3/4: Si53102-A3

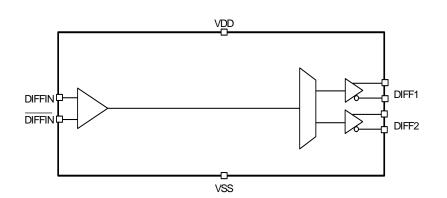
Applications

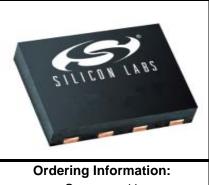
- Network Attached Storage
- Multi-function Printer
- Wireless Access Point
- Server/Storage

Description

Si53102-A1/A2/A3 is a family of high-performance 1:2 PCle fan output buffers. This low-additive-jitter clock buffer family is compliant to PCle Gen 1, Gen 2, Gen 3, and Gen 4 specifications. The ultra-small footprint (1.4x1.6 mm) and industry-leading low power consumption make the Si53102-A1/A2/A3 the ideal clock solution for consumer and embedded applications. Measuring PCle clock jitter is quick and easy with the Silicon Labs PCle Clock Jitter Tool. Download it for free at www.silabs.com/pcielearningcenter.

Functional Block Diagram







Pin Assignments						
DIFFIN	• 1)	(8	VDD			
DIFFIN	2)	(7	DIFF2			
DIFF1	3)	(6	DIFF2			
DIFF1	4)	(5	vss			

Patents pending



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1. Electrical Specifications

Table 1. Recommended Operating Conditions

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Supply Voltage (3.3 V Supply)	V _{DD}	3.3 V ± 10%	2.97	3.3	3.63	V
Supply Voltage (2.5 V Supply)	V _{DD}	2.5 V ± 10%	2.25	2.5	2.75	V

Table 2. DC Electrical Specifications

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Operating Voltage (VDD = 3.3 V)	V _{DD}	3.3 V ± 10%	2.97	3.30	3.63	V
Operating Voltage (VDD = 2.5 V)	V _{DD}	2.5 V ± 10%	2.25	2.5	2.75	V
Operating Supply Current	I _{DD}	Full Active		—	12	mA
Input Pin Capacitance	C _{IN}	Input Pin Capacitance	—	3	5	pF
Output Pin Capacitance	C _{OUT}	Output Pin Capacitance	—	—	5	pF



Parameter	Symbol	Condition	Min	Тур	Max	Unit
DIFFIN at 0.7 V	-					
Input frequency	Fin		10	100	175	MHz
DIFFIN and DIFFIN Rising/Falling Slew Rate	T _R / T _F	$ \begin{array}{c c} T_{R} \ / \ T_{F} & Single \ ended \ measurement: \\ V_{OL} = 0.175 \ to \ V_{OH} = 0.525 \ V \\ & (Averaged) \end{array} $		—	4	V/ns
Differential Input High Voltage	V _{IH}	V _{IH}		—	_	mV
Differential Input Low Voltage	V _{IL}		—	—	-150	mV
Crossing Point Voltage at 0.7 V Swing	V _{OX}	Single-ended measurement	250	—	550	mV
Vcross Variation Over All edges	ΔV_{OX}	Single-ended measurement	_		140	mV
Differential Ringback Voltage	V _{RB}		-100	—	100	mV
Time before Ringback Allowed	T _{STABLE}		500	—	_	ps
Absolute Maximum Input Voltage	V _{MAX}			—	1.15	V
Absolute Minimum Input Voltage	V _{MIN}		-0.3	—	_	V
DIFFIN and DIFFIN Duty Cycle	T _{DC}	Measured at crossing point V_{OX}	45	—	55	%
Rise/Fall Matching	T _{RFM}	Determined as a fraction of $2 \times (T_R - T_F)/(T_R + T_F)$	—	—	20	%
DIFF Clocks						
Duty Cycle	T _{DC}	Measured at crossing point V_{OX}	45	_	55	%
Output Skew	T _{SKEW}	Measured at 0 V differential		—	100	ps
Frequency Accuracy	F _{ACC}	All output clocks	—	—	100	ppm
Slew Rate	t _{r/f2}	Measured differentially from ±150 mV	0.6	—	4.0	V/ns
PCIe Gen 1 Pk-Pk Additive Jitter	Pk- Pk _{GEN1}	PCIe Gen 1 Si53102-A1	_	—	10	ps
PCIe Gen 2 Additive Phase Jitter	RMS _{GEN2}	10 kHz < F < 1.5 MHz, Si53102-A2	-	—	0.50	ps
PCIe Gen 2 Additive Phase Jitter	RMS _{GEN2}	1.5 MHz < F < Nyquist, Si53102-A2	—	—	0.50	ps
PCIe Gen 3 Additive Phase Jitter	RMS _{GEN3}	Includes PLL BW 2–4 MHz, CDR = 10 MHz, Si53102-A3	_	—	0.20	ps
PCIe Gen 4 Additive Phase Jitter	RMS _{GEN4}	PCIe Gen 4		—	0.20	ps
Crossing Point Voltage at 0.7 V Swing	V _{OX}		300	—	550	mV
Enable/Disable and Setup				I		
Clock Stabilization from Powerup	T _{STABLE}	Power up to first output	—	_	3.0	ms
Notes:		-	1	I]		

1. Visit www.pcisig.com for complete PCIe specifications.

2. Gen 4 specifications based on the PCI-Express Base Specification 4.0 rev. 0.5.

3. Download the Silicon Labs PCIe Clock Jitter Tool at www.silabs.com/pcie-learningcenter.



Si53102-A1/A2/A3

Table 4. Thermal Conditions

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Temperature, Storage	Τ _S	Non-functional	-65		150	°C
Temperature, Operating Ambient	T _A	Functional	-40		85	°C
Temperature, Junction	TJ	Functional	_		150	°C
Dissipation, Junction to Case	θ_{JC}	JEDEC (JESD 51)	_		38.3	°C/W
Dissipation, Junction to Ambient	θ_{JA}	JEDEC (JESD 51)	_		90.4	°C/W

Table 5. Absolute Maximum Conditions

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Main Supply Voltage	V _{DD_3.3V}		_		4.6	V
Input Voltage	V _{IN}	Relative to V _{SS}	-0.5		4.6	V _{DC}
ESD Protection (Human Body Model)	ESD _{HBM}	JEDEC (JESD 22-A114)	2000			V
Flammability Rating UL-94 UL (Class) V–0						
Note: While using multiple power supplies, the voltage on any input or I/O pin cannot exceed the power pin during powerup. Power supply sequencing is NOT required.						



2. Test and Measurement Setup

Figures 1 through 3 show the test load configuration for the differential clock signals.

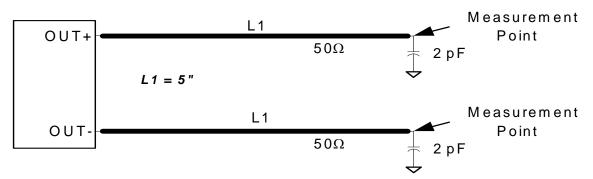


Figure 1. 0.7 V Differential Load Configuration

The outputs from this device can also support LVDS, LVPECL, or CML differential signaling levels using alternative termination. For recommendations on how to achieve this, see "AN781: Alternative Output Termination for Si5213x, Si5214x, Si5121x, and Si5315x PCIe Clock Generator and Buffer Families" at www.silabs.com.

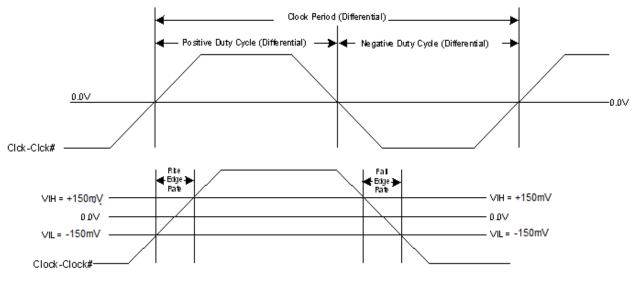
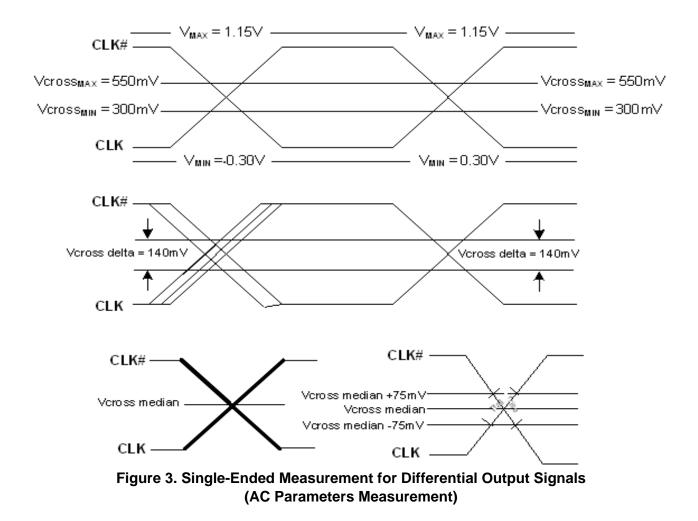


Figure 2. Differential Measurement for Differential Output Signals (AC Parameters Measurement)

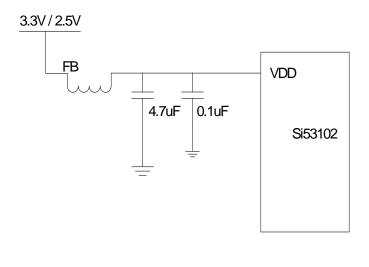


Si53102-A1/A2/A3





3. Recommended Design Guideline



Note: FB Specifications: DC resistance $0.1-0.3 \Omega$ Impedance at 100 MHz \geq 1000 Ω

Figure 4. Recommended Application Schematic



4. Pin Descriptions

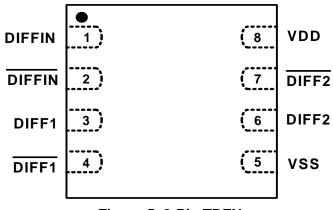


Figure 5. 8-Pin TDFN

Table 6. Si53102-Ax-GM 8-Pin TDFN Descriptions

Pin #	Name	Туре	Description
1	DIFFIN	O, DIF	0.7 V, 100 MHz differentials clock input
2	DIFFIN	O, DIF	0.7 V, 100 MHz differentials clock input
3	DIFF1	O, DIF	0.7 V, 100 MHz differential clock output
4	DIFF1	O, DIF	0.7 V, 100 MHz differential clock output
5	GND	GND	Ground
6	DIFF2	O, DIF	0.7 V, 100 MHz differential clock output
7	DIFF2	O, DIF	0.7 V, 100 MHz differential clock output
8	VDD	PWR	2.5 V or 3.3 V Power supply



5. Ordering Guide

Part Number	Package Type	Temperature
Si53102-A1-GM	8-pin TDFN	Extended, -40 to 85 °C
Si53102-A1-GMR	8-pin TDFN—Tape and Reel	Extended, -40 to 85 °C
Si53102-A2-GM	8-pin TDFN	Extended, -40 to 85 °C
Si53102-A2-GMR	8-pin TDFN—Tape and Reel	Extended, -40 to 85 °C
Si53102-A3-GM	8-pin TDFN	Extended, -40 to 85 °C
Si53102-A3-GMR	8-pin TDFN—Tape and Reel	Extended, –40 to 85 °C



6. Package Outlines

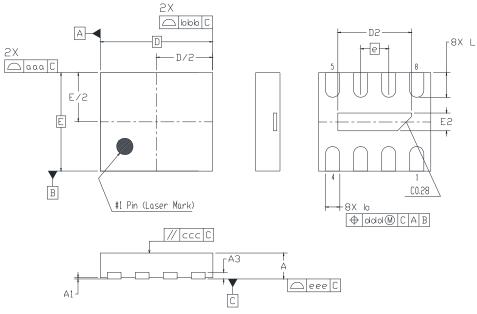


Figure 6. 8-Pin TDFN Package Drawing

Dimension	Min	Nom	Max		
A	0.70	0.75	0.80		
A1	0.00	0.02	0.05		
A3		0.20 REF.			
b	0.15	0.20	0.25		
D	1.60 BSC				
D2	1.00	1.05	1.10		
е	0.40 BSC				
E		1.40 BSC			
E2	0.20	0.25	0.30		
L	0.30	0.35	0.40		
aaa		0.10			
bbb	0.10				
CCC	0.10				
ddd	0.07				
eee	0.08				
Notes:					

Table 7. Package Diagram Dimensions

Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



7. PCB Land Pattern

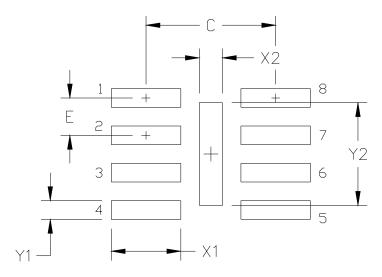


Figure 7. Si53102 8-Pin TDFN Land Pattern

Table 8. Si53102	8-Pin Land	Pattern	Dimensions
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Dimension	mm
С	1.40
E	0.40
X1	0.75
Y1	0.20
X2	0.25
Y2	1.10
 Notes: General 1. All dimensions shown are in millimeters (mm). 2. This Land Pattern Design is based on the IPC-7351 guidelines. 3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm. 	
Solder Mask Design4. All metal pads are to be non-solder mask defined (NSMD). Clearance	
between the solder mask and the metal had is to be 60 um minimum, all the	

between the solder mask and the metal pad is to be 60 μm minimum, all the way around the pad.

Stencil Design

- **5.** A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 6. The stencil thickness should be 0.125 mm (5 mils).

7. The ratio of stencil aperture to land pad size should be 1:1 for all pads.

Card Assembly

8. A No-Clean, Type-3 solder paste is recommended.

9. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.



DOCUMENT CHANGE LIST

Revision 0.4 to Revision 1.0

- Updated Table 3 on page 5.
 - Updated input frequency min and max specs.
- Updated "2. Test and Measurement Setup" on page 7.
 - Added text and reference to AN781.

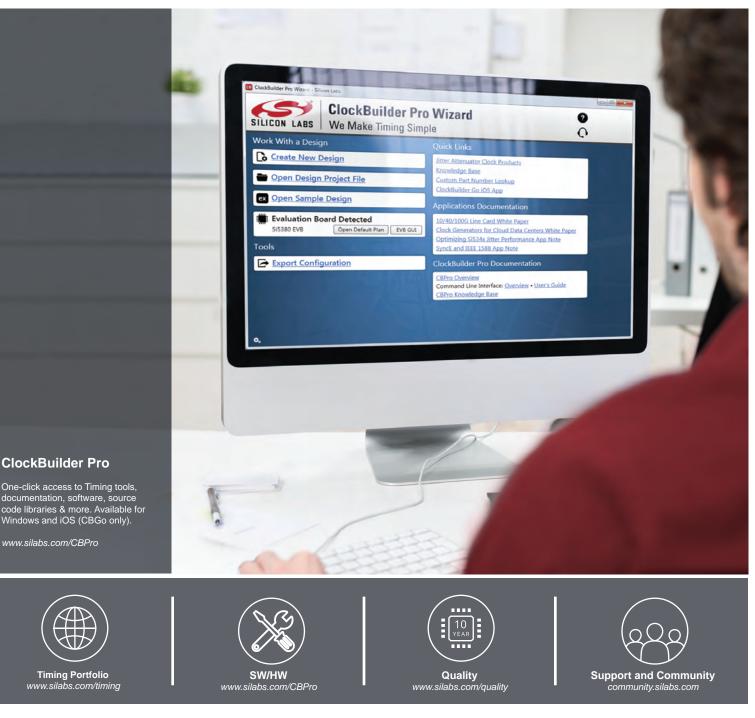
Revision 1.0 to Revision 1.1

- Moved "3. Recommended Design Guideline" to page 9.
- Corrected Figure 5 title on page 10.
- Corrected Table 6 title on page 10.
- Corrected Figure 6 title on page 12.
- Added "7. PCB Land Pattern" on page 13.

Revision 1.1 to Revision 1.2

- Updated Features on page 1.
- Updated Description on page 1.
- Updated specs in Table 3, "AC Electrical Specifications," on page 5.





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